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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/026,020	12/27/2001	Ralph H. Johnson	15436.436.5	6112
22913	7590 11/03/2004		EXAMINER	
WORKMAN NYDEGGER (F/K/A WORKMAN NYDEGGER & SEELEY) 60 EAST SOUTH TEMPLE 1000 EAGLE GATE TOWER			NGUYEN, DUNG T	
			ART UNIT	PAPER NUMBER
			2828	
SALT LAKE	CITY, UT 84111		DATE MAILED: 11/03/200	4

Please find below and/or attached an Office communication concerning this application or proceeding.

3				AV		
Office Action Summary		Application No.	Applicant(s)			
		10/026,020	JOHNSON, RALPH I	H.		
		Examiner	Art Unit			
		Dung (Michael) T Nguyen	2828			
	The MAILING DATE of this communication app	ears on the cover sheet with	the correspondence addre	ss		
Period fo		/ 10 OFT TO EVEIDE 1401	ITI I/O) EDOM			
THE - Exte after - If the - If NO - Failu Any	ORTENED STATUTORY PERIOD FOR REPLY MAILING DATE OF THIS COMMUNICATION. nsions of time may be available under the provisions of 37 CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. Period for reply specified above is less than thirty (30) days, a reply of period for reply is specified above, the maximum statutory period we are to reply within the set or extended period for reply will, by statute, reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	66(a). In no event, however, may a reply within the statutory minimum of thirty (3 ill apply and will expire SIX (6) MONTH cause the application to become ABAN	be timely filed  0) days will be considered timely.  S from the mailing date of this comm  DONED (35 U.S.C. § 133).	ıunication.		
Status	o					
1)⊠	Responsive to communication(s) filed on 28 Ju	<u>ıly 2004</u> .				
2a)⊠	This action is <b>FINAL</b> . 2b) ☐ This	action is non-final.				
3)□	• •	•	• •	erits is		
	closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 1	1, 453 O.G. 213.			
Disposit	ion of Claims					
4)⊠	Claim(s) 1-28 and 45-59 is/are pending in the a	application.				
	4a) Of the above claim(s) is/are withdraw	vn from consideration.				
5)□	Claim(s) is/are allowed.					
·	☑ Claim(s) <u>1-28,45-59</u> is/are rejected.					
·	Claim(s) is/are objected to.					
8)	Claim(s) are subject to restriction and/or	r election requirement.	-			
Applicat	ion Paperş					
9)[	The specification is objected to by the Examine	r.				
10)	The drawing(s) filed on is/are: a) acce	epted or b) objected to by	the Examiner.			
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
	Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).					
11)	The oath or declaration is objected to by the Ex	aminer. Note the attached C	Office Action or form PTO-	152.		
Priority (	under 35 U.S.C. § 119					
a)	Acknowledgment is made of a claim for foreign  All b) Some * c) None of:  1. Certified copies of the priority documents  2. Certified copies of the priority documents  3. Copies of the certified copies of the priority application from the International Bureau  See the attached detailed Office action for a list	s have been received. s have been received in App ity documents have been re ı (PCT Rule 17.2(a)).	lication No ceived in this National Sta	age		
Attachmen	t(s)					
	ce of References Cited (PTO-892)	4) Interview Sum				
	ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08)		/lail Date ∙mal Patent Application (PTO-15	52)		
	Pr No(s)/Mail Date <u>03/08/04</u> .	6) Other:	, ,			

Application/Control Number: 10/026,020

Art Unit: 2828

### **DETAILED ACTION**

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-28 and 45-59 are rejected under 35 U.S.C. 103(a) as being unpatentable over Jewell et al (US6359920) in view of Ishikawa (US5841152).

With respect to claims 1-28 and 45-59, Jewell et al disclose a VCSEL (100) comprising an active region (110) further comprising at least one quantum well (126, 128) of GaAsSb having a depth of 40meV (Fig.2b) and further including GaAs barrier layer (54') sandwiching said at least one quantum well and GaAs confinement layer (70') sandwiching said active region and nitrogen to be used at least 1% in group V of semiconductor material in the active region. Jewell also disclose alternative substitution elements such as In, Al, N, Sb with the basic material GaAs and the quantum well is up to and including 50 Å, note col. 5 line

Art Unit: 2828

24 to col. 37 line 18, see figures 1-11. However; Jewell do not disclose the quantum well depth is defined as the difference between a valence band offset and a conduction band offset. Ishikawa teaches the quantum well depth is defined as the difference between a valence band offset and a conduction band offset (col.5, 1.13-15). For the benefit of calculating the quantum well depth, it would have been obvious to one having ordinary skill in the art at the time the invention was made to provide Jewell the quantum well depth is defined as the difference between a valence band offset and a conduction band offset as taught by Ishikawa.

#### Conclusion

Responding on the remark filed on 07/28/2004 for reconsideration, the examiner maintains the rejection mailed on 12/19/2003.

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire

THREE MONTHS from the mailing date of this action. In the event a first reply is

filed within TWO MONTHS of the mailing date of this final action and the

advisory action is not mailed until after the end of the THREE-MONTH shortened

Art Unit: 2828

statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Page 4

## **Communication Information**

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Dung (Michael) T Nguyen whose telephone number is (571) 272-1949. The examiner can normally be reached on 8:30 - 17:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Min Harvey can be reached on (571) 272-1835. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 306-3329.

Michael Dung Nguyen

MINSUN OH HARVEY